### 2SD2096

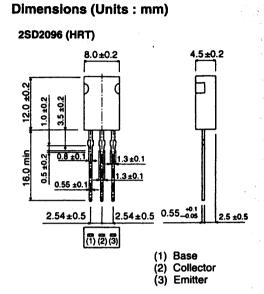
## **Transistor, NPN**

#### **Features**

- available in HRT package
- low collector saturation voltage, typically V<sub>CE(sat)</sub> = 0.3 V at I<sub>C</sub>/I<sub>B</sub> = 2 A/ 0.2 A
- excellent current-to-gain characteristics
- large collector loss: P<sub>C</sub> = 1.8 W
- wide safe operating area (SOA)

#### **Applications**

low frequency power amplifier



### Absolute maximum ratings $(T_a = 25^{\circ}C)$

Parameter	Symbol	Limits	Unit	Conditions
Collector-to-base voltage	V <sub>CBO</sub>	80	V	
Collector-to-emitter voltage	V <sub>CEO</sub>	60	V	
Emitter-to-base voltage	V <sub>EBO</sub>	5	V	
Collector current	l <sub>C</sub>	3	Α	Continuous (dc)
		6	Α	Single pulse, P <sub>W</sub> = 100 ms
Collector dissipation	Pc	1.8	W	
Junction temperature	T,	150	°C	
Storage temperature	T <sub>stg</sub>	-55 ~ +150	°C	

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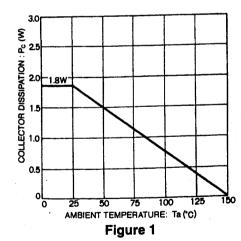
# Electrical characteristics (unless otherwise noted, $T_a = 25$ °C)

Parameter	Symbol	Min	Typical	Max	Unit	Conditions
Collector-to-base breakdown voltage	BV <sub>CBO</sub>	80			٧	I <sub>C</sub> = 50 μA
Collector-to-emitter breakdown voltage	BV <sub>CEO</sub>	60			V	I <sub>C</sub> = 1 mA
Emitter-to-base breakdown voltage	BV <sub>EBO</sub>	5			V	I <sub>E</sub> = 50 μA
Collector cutoff current	Ісво			10	μА	V <sub>CB</sub> = 60 V
Emitter cutoff current	I <sub>EBO</sub>			10	μΑ	V <sub>EB</sub> = 4 V
DC current gain	h <sub>FE</sub>	60		320		$V_{CE} = 5 \text{ V}$ , $I_{C} = 0.5 \text{ A}$ , single pulse
Collector-to-emitter saturation voltage	V <sub>CE(sat)</sub>		0.3	1.0	V	$I_{\rm C}/I_{\rm B} = 2$ A/0.2 A, single pulse
Base-to-emitter saturation voltage	V <sub>BE(sat)</sub>			1.5	V	$I_{\text{C}}/I_{\text{B}} = 2 \text{ A}/0.2 \text{ A, single pulse}$
Transition frequency	f <sub>T</sub>		8		MHz	$V_{CE} = 5 \text{ V}, I_{E} = -0.5 \text{ A}, f = 5 \text{ MHz}$
Output capacitance	C <sub>ob</sub>		70		pF	$V_{CB} = 10 \text{ V}, I_E = 0 \text{ A}, f = 1 \text{ MHz}$

### h<sub>FE</sub> rankings

	Item	D	E	F	
į	h <sub>FE</sub>	60 ~ 120	100 ~ 200	160 ~ 320	

#### **Electrical characteristic curves**



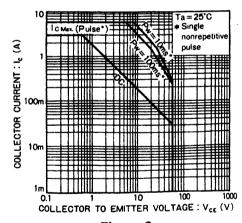
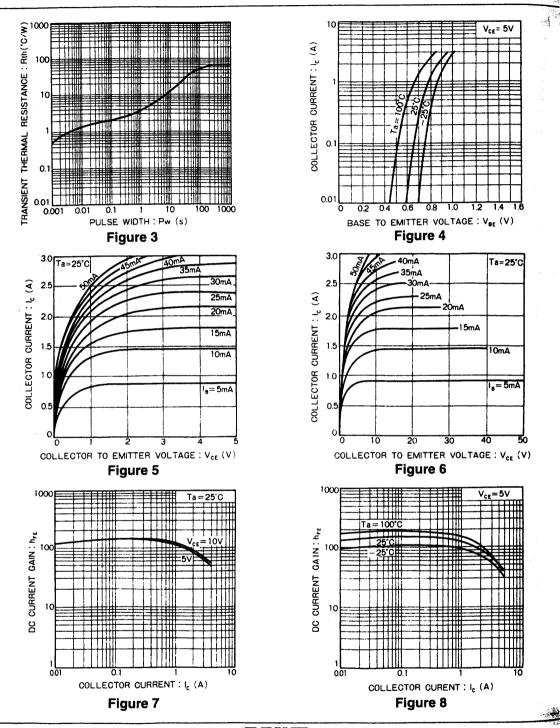
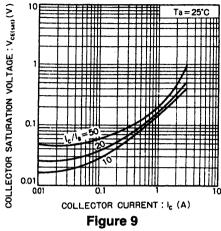


Figure 2





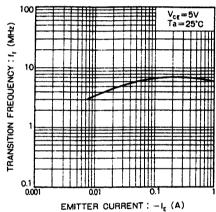


Figure 11

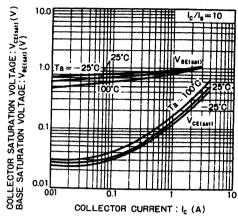


Figure 10

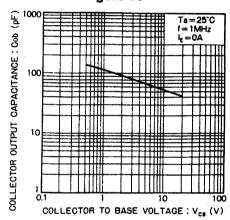


Figure 12

### **Ordering information**

Package	Tape	
Code	T114	
Basic order quantity	1 000	
2SD2096 ★		
* = Standard, ☆ = Semi-standard, * = Special order		

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